## NSN 5961-00-115-8477

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-115-8477 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.104 inches **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Gate **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 10.0 reverse voltage, dc and 1.5 forward voltage, average **Current Rating Per Characteristic:** 150.00 milliamperes source cutoff current preset and 20.00 milliamperes forward current, total rms peak **Power Rating Per Characteristic:** 150.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Internal junction configuration arrangement pnpn **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 80131-release5303 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0